NSN 5961-01-286-7276

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View Online at https://aerobasegroup.com/nsn/5961-01-286-7276 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.500 inches **Overall Height:** 1.500 inches **Overall Width:** 0.469 inches **End Application:** Non directional beacon, receiver model sr115 (ndbsr115) **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): 27 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 115.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 solder stud and 1 case Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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